



Operating temperature dependent ethanol and formaldehyde detection of spray deposited mixed CdO and MnO₂ thin films

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Operating temperature dependent ethanol and formaldehyde detection of spray deposited mixed CdO and MnO₂ thin films

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Abstract

The CdO-MnO₂ mixed oxide films are synthesized using spray pyrolysis method. The structural study confirms polycrystalline nature of the film and also confirms that the films are in mixed oxide state. The morphological study reveals that the crystallite sizes are around 30 nm to 40 nm with spherical morphology. Energy dispersive spectroscopy confirms the presence of cadmium, manganese and oxygen in mixed oxide state. The prepared CdO-MnO₂ film is highly sensitive to ethanol vapours at ambient temperature. The resistance of the film decreases drastically when exposed to ethanol and formaldehyde vapours. The prepared CdO-MnO₂ is highly sensitive to ethanol at ambient temperature and for formaldehyde vapour at 393 K. The sensitivity, selectivity, response time, recovery time and stability of CdO-MnO₂ film towards ethanol and formaldehyde sensing are reported in the present work.

Keywords: Mixed oxide, Nanostructure, Sensitivity, Selectivity, Response time, Recovery time

1. Introduction

Metal oxide semiconductors such as SnO₂, ZnO, Bi₂O₃, TiO₂, Ga₂O₃, Fe₂O₃ are widely used for the detection of toxic gases such as CO, H₂S, NO₂ and volatile organic compounds (VOCs) such as CH₄, C₂H₅OH, C₃H₈, benzene, acetone etc.¹⁻⁸ Conductometric sensors based on metal oxides are commonly used as gas sensors to monitor toxic vapours in the environment. When the threshold limit of these toxic gases or vapours exceeds it will have harmful effects on humans and also to the ecosystem. The gas sensing mechanism of metal oxide type gas sensors involves the chemisorption of oxygen from air atmosphere on to the base material creating the space charge layer around the nanostructure in the base material, when the target gas molecules interacts with chemisorbed oxygen on metal oxide results in charge transfer to takes place between the base material and oxygen resulting in change in the surface resistance of sensing element.⁹ However, the gas sensing properties of metal oxide varies due to various factors such as morphology, nano-dimension, porosity, catalytic activity, surface chemical properties and activation energy.¹⁰⁻¹⁶ The sensitivity and selectivity of target gas to a particular material is a challenging task in gas sensing. Nevertheless, most of the mechanism involves between the adsorbed oxygen and target gas, the working temperature is usually high to activate the sensing process. To overcome all these difficulties and to enhance the sensing properties towards the gas or vapour there is need for smart gas sensor which can be operated at ambient temperature with enhanced sensing response. Based on these aspects, literature survey was conducted and it is inferred that most of the reported works are in gas sensing studies on metal oxide thin films or nanoparticles towards target gas.¹⁷⁻²⁰ We have reported the ethanol sensing properties of cadmium oxide.²¹ To date, not much work has been reported based on cadmium oxide (CdO) and manganese oxide (MnO₂) on ethanol and formaldehyde vapour sensing. The novel aspect of the

present work is to enhance the sensing properties towards ethanol and formaldehyde with nanostructured mixed oxide (CdO-MnO₂) thin film. The CdO-MnO₂ mixed oxide is highly sensitive towards ethanol and formaldehyde at different operating temperatures. The sensing properties are fine-tuned by synthesizing the mixed oxide CdO-MnO₂ in nanostructured form. In the present work, CdO and MnO₂ thin films are synthesized and the vapour sensing characteristics are studied and reported.

2. Materials and methods

2.1 Thin film preparation

Mixed oxides of cadmium oxides and manganese oxides are deposited onto the glass substrate by home-built spray pyrolysis unit.²² Cadmium acetate dihydrate [(CH₃COO)₂Cd.2H₂O, 99.9% purity, Nice] is used as precursor salt of 0.05M is dissolved in 25 mL deionized water. Manganese acetate tetrahydrate [(CH₃COO)₂Mn.4H₂O, 99.9% purity, Qualigens] is used as precursor salt of 0.05 M is dissolved in 25 mL deionized water. Then both solutions are mixed together to make up a solution of 50mL and stirred in the magnetic stirrer for half an hour for the preparation of precursor solution. The precursor solution is then atomized as a fine mist by air compressor through a glass nozzle and sprayed on to the pre-heated glass substrate at an angle of 45°. The temperature of the glass substrate is maintained at a temperature of 230±1°C with a thermostat fitted with K-type thermocouple. Many samples are deposited by varying the substrate temperature and for different thickness to find the optimized condition for uniform distribution of nanocrystallites over the glass substrate. Finally, it was observed that for the deposition temperature of around 230°C, the precursor solution vaporizes and uniform thin film is deposited on the glass substrate. For low substrate temperature the deposition results in incomplete pyrolytic reaction with partial decomposition of precursor salt. Hence, for uniform

coating of mixed oxides the substrate temperature is maintained at 230°C. The compressed dry air with a pressure of 2kg/cm² is used as carrier gas and the distance between the glass substrate and atomizer is maintained at a distance of 30 cm. In order to obtain a uniform coating the precursor solution is sprayed onto the glass substrate with the time duration of 5 s at an interval of 60 s.

2.2 Characterization

Structural studies for the mixed oxide (CdO-MnO₂) film is carried out using Bruker – D8 Focus X-Ray Diffraction (XRD) Unit with Cu K α ₁ radiation with the generator setting of 30 mA and 40 kV. The surface morphology and elemental identification of the film are obtained from JEOL-6701 Field-Emission Scanning Electron Microscopy (FE-SEM) with Energy dispersive X-ray analysis (EDAX) detector. The optical studies of mixed oxide CdO-MnO₂ thin films were carried out using UV-Visible spectrophotometer (Perkin Elmer Lambda 25). The film thickness is measured by stylus profilometer (Mitutoyo SJ 301) and the thickness of the mixed oxide CdO-MnO₂ films is found to be around 500 nm.

2.3 Vapour sensing setup

For vapour sensing studies, home-built vapour sensing unit is used with thermostat. The capacity of the test chamber is 1.5 L. Initially, the thin film is conditioned at 300°C for 24 hours to remove the water molecules and unwanted organic materials. The ohmic contacts are made on to the thin film (12mm x 10 mm) with thin copper wire and silver epoxy. The change in the electrical resistance of the film is recorded using National Instruments Data Acquisition board (NI DAQ 6212) during the process of injecting and evacuating ethanol and formaldehyde vapours. The dry ethanol is procured from Sigma-Aldrich [Pure, anhydrous, \geq 99.5%, 459836] and used as such without further purification. The electrical resistance of thin film in dry air is in

the order of GΩ and this resistance is taken as the baseline resistance (R_0) in the present study. For sensing studies, calibrated volume of ethanol and formaldehyde is introduced into the test chamber and the response of the film towards the vapours is studied.

2.4 Computational details

In the proposed model, mixed oxide CdO-MnO₂ is taken as scattering region between two gold electrodes. The left electrode is kept at two volts and the right electrode is kept at constant ground potential. The proposed model is constructed and optimized using TranSIESTA module in SIESTA package. In SIESTA code, the core electrons are replaced by pseudopotentials. The generalized gradient approximation (GGA) with Perdew-Burke-Ernzerhof (PBE) exchange correlation functional is used during calculation. The Brillouin zones are sampled with 1 x 1 x 100 k points in the present model. The optimization of molecular device is carried out with single zeta polarization for gold atoms and double zeta polarization for cadmium, manganese and oxygen atoms in the present model.

3. Results and discussion

3.1 Structural studies

The X-ray diffraction (XRD) pattern of mixed oxide CdO-MnO₂ is shown in Fig. 1. The orientation of planes for both CdO and MnO₂ confirms the polycrystalline nature. The peaks at different 2θ values exactly matches with JCPDS card number 05-0640 for CdO and JCPDS card number 42-1169 for MnO₂. This also confirms that the prepared films are not ternary compound but in mixed oxide state. The crystallite size was estimated using known Scherrer formula,

$$D = \frac{S \times \lambda}{\beta \times \cos \theta} \text{-----(1)}$$

where D represents the crystallite size (nm), S denotes the shape factor which is equal to 0.9, λ is X-ray wavelength (1.5406 Å), θ is the diffraction angle (radians) and β is full width at half maximum (FWHM in radians). The X-ray line broadening clearly infers that the crystallite of CdO-MnO₂ is in nanometric regime. The calculated crystallite size of CdO-MnO₂ mixed oxide is found to be around 30 nm to 40 nm from the Scherrer formula.

3.2 Morphological studies and elemental analysis

Fig. 2 represents the field-emission scanning electron micrograph (FE-SEM) of mixed oxide CdO-MnO₂ thin film. The synthesized film exhibits the spherical morphology with porosity. For the optimized preparatory condition with respect to concentration of precursor solution and substrate temperature, the prepared CdO-MnO₂ film shows spherical like morphology. The formation of worm-like structure is due to the influence of electrostatic mechanism, which arises due to the possibility of exchange of free electrons between nanocrystallites among small intercrystallite distances.²³ The crystallite size of prepared films is observed to be around 30nm to 40nm which is also in good agreement with the calculated value of crystallite size using Scherrer formula in XRD. Fig. 3 illustrates the energy dispersive X-ray analysis (EDAX) spectrum. It is clearly inferred that the synthesized mixed oxide film shows the presence of elements cadmium, manganese, oxygen and silicon. The presence of element silicon in the spectrum is due to glass substrate. Since the atomic number of cadmium is forty eight, $L\alpha$ line in EDAX spectrum is observed near 3.2 eV. Moreover, for manganese and oxygen $K\alpha$ lines are observed in lower energies. Fig. 4 depicts the mapping of elements for the prepared film. It is clearly observed that in the mixed configuration, the elements oxygen, silicon, manganese and cadmium are noticed (color gradient shows the presence of elements). The positions of individual elements in thin films are mapped separately. From the map, it is clearly inferred that

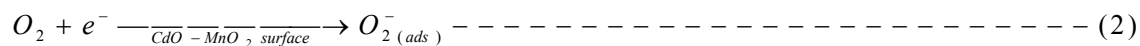
the formed thin film is in mixed oxide state with CdO and MnO₂ and not as a ternary compound. The map of elements in EDAX spectrum is in good agreement with XRD which also confirms the mixed oxide state of the film.

3.3. Optical studies

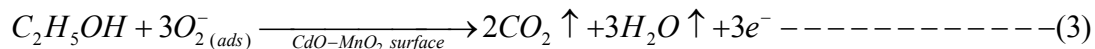
The optical properties for the mixed oxide CdO-MnO₂ are studied within the wavelength range of 300 nm to 1100 nm. The visual appearance of the prepared film is glassy black in color. The transmittance of mixed oxide CdO-MnO₂ is shown in Fig. 5. The transmittance of the film is in the order of 20% to 50% in the visible region. The drastic variation in transmittance is observed for CdO-MnO₂ mixed oxide film in visible region. Moreover, the transmittance increases to nearly 70% in the infra-red region. The low magnitude of transmission in the visible region supports the polycrystalline nature of the film with high surface roughness, which is a favorable condition for chemical sensors.²⁴ The optical band gap of the CdO-MnO₂ mixed oxide film is obtained from Tauc's plot and is depicted in Fig. 6. The optical band gap of MnO₂ are reported as 2.5 eV and for CdO²⁵, the reported optical band gap is around 2.3 eV.²¹ However, in the mixed oxide state of CdO-MnO₂, the optical band gap increases to 2.7 eV.

3.4 Ethanol vapour sensing mechanism

Ethanol is a colorless, inflammable volatile organic compound found in alcoholic beverages.^{26, 27} The use of ethanol also wide spread in medicine, chemical industry and in food industry.^{28, 29} Ethanol causes the harmful effects in human which depends on the concentration. The higher dose of ethanol vapours results in mild euphoria to severe depression in central nervous system.³⁰ This necessitated the detection level of ethanol in the order of parts per million (ppm) level. At first, the mixed oxide CdO-MnO₂ film is exposed to air atmosphere, the oxygen molecules are adsorbed as molecular oxygen ions O₂⁻ at low temperatures as given in Eq. (2),



When the mixed oxide CdO-MnO₂ films is exposed to ethanol vapours, nanocrystallites of CdO-MnO₂ present on the surface shows a catalytic activity³¹ with the exothermic reaction between the adsorbed oxygen ions and ethanol and can be represented as Eq. 2. We have reported the ethanol sensing characteristics of CdO thin film.²¹ However, the ethanol sensing is feasible only at the temperature of 523 K. The ethanol sensing response for pure CdO and pure MnO₂ thin films is found to be around 0% at ambient temperature. In contrast, the response is optimum in the mixed oxide state for ethanol sensing. The adsorbed oxygen ions in the mixed oxide film are desorbed by oxidation of ethanol vapours. The consumed electrons by the oxygen ion from the conduction of the mixed oxide films are released back to the mixed oxide film which decreases the resistance of the film. This process reduces the electrical resistance of the mixed oxide CdO-MnO₂ film. This change in the resistance of the mixed oxide film is utilized in detecting the ethanol vapours. The oxidation of ethanol vapours takes place in the ambient air.^{32,33} For the catalytic activity to take place, usually activation energy is required in the form of thermal energy or optical energy. Interestingly, in the case of mixed oxide CdO-MnO₂ thin film, it shows the response at ambient temperature for ethanol vapours.



The sensing response of mixed oxide CdO-MnO₂ can be estimated using the following expression as

$$\% S = \frac{(R_o - R_g)}{R_g} \times 100 \text{-----} (4)$$

where R_o and R_g are the electrical resistance of the film in the presence of air and in presence of ethanol vapour under dry-air atmosphere respectively. The sensing response of mixed oxide CdO-MnO₂ increases enormously with increase in ethanol concentration as shown in Fig. 7. The electrical resistance of the mixed oxide film at ambient air is around 1GΩ. However, when CdO-MnO₂ film is exposed to ethanol vapours, the resistance of mixed oxide film drastically decreases to 0.625 GΩ for 15 ppm concentration. Besides, increase in the concentration of ethanol result in decrease of resistance to 0.55 GΩ.

Fig. 8a-b illustrates the proposed model of CdO-MnO₂ mixed oxide two probe molecular device. The adsorption characteristics of ethanol are carried out on different sites of CdO-MnO₂ scattering region. The current-voltage characteristics of the proposed model are studied in this state. Moreover, when ethanol gets adsorbed on cadmium site, there is no significant response. Interestingly, in the optimized condition, when hydroxyl group in the ethanol molecule gets adsorbed on to manganese atom of mixed CdO-MnO₂, the response increases. This clearly infers that when ethanol molecule gets adsorbed on to the mixed oxide, transfer of electrons takes place between the mixed oxide and ethanol which is confirmed with change in the current.^{34,35} The theoretical model also supports that in the mixed oxide state the transfer of electrons increases which in turn is observed by the increase in the current. The proposed model is used to validate the experimental results of the present work. The response towards ethanol is not significant in pure CdO and pure MnO₂ at ambient temperature. Despite, in mixed oxide state, the response is more promising, which can be highlighted that only in mixed oxide state ethanol gets oxidized and dissociates in the base material. However, the present study is carried out for ethanol on CdO-MnO₂ scattering region only at ambient temperature. Due to constraints in software

package, the study is not carried out at elevated temperature. Moreover, in future the proposed model may be extended for elevated temperature.

3.5. Response and recovery studies of Ethanol

The transient resistance response of mixed oxide CdO-MnO₂ thin film is investigated with ethanol vapour concentration ranging from 15 ppm to 75 ppm at ambient temperature (300 K). Fig. 9 depicts the transient response of CdO-MnO₂ films towards various concentrations. However, on increasing the ethanol concentration the resistance drops further to the low value. Moreover, beyond the concentration of 75 ppm there is not much variation in the resistance. This shows that for higher concentration ethanol vapours completely depletes the grains in the mixed oxide film and there is no further decrease in the resistance. This infers that the prepared mixed oxide CdO-MnO₂ film can be used to detect ethanol vapour in the order of 15 ppm to 75 ppm. Fig. 10 represents the repeatability curve of ethanol for 30 ppm; it clearly signifies that for different cycles of operation the trend in the variation of resistance is almost same. Fig. 11 shows the response time and recovery time versus concentration of ethanol vapours. It indicates the fast response time and a slow recovery time when the concentration of ethanol increases. For small crystallite size of 30 nm to 40 nm, it leads to rapid response-recovery behavior in the order of seconds. For lower concentrations, desorption of oxygen ions requires more time so the response time is more. In contrast, for higher concentrations, the vapour rapidly desorbs oxygen ions and the response time is rapid.³⁶ However, for recovery time it takes more time since the ethanol are completely depleted over the crystallites in the mixed oxide film. Fig. 12 represents the sensing response and selectivity of CdO-MnO₂ mixed oxide for ethanol and various other volatile organic compounds (VOCs) at ambient temperature of 300 K. The sensor response for 15 ppm ethanol is around 61 % compared with other VOCs such as formaldehyde, acetone, CCl₄ and

1,2-dichloroethylene. When the concentration of ethanol and other VOCs increases the response also increases. However, CdO-MnO₂ mixed oxide film is highly sensitive and selective towards ethanol vapours than other VOCs at ambient temperature. Moreover, for higher concentration of ethanol, the mixed CdO-MnO₂ film shows better response. From the response to other VOCs plot, it can be concluded that the prepared mixed oxide CdO-MnO₂ is highly sensitive towards ethanol vapour at ambient temperature. Table 1 represents the ethanol sensing studies of different chemiresistive sensors.³⁷⁻⁴³ In previously reported work the response and recovery time is more or the sensor is operated at high temperature for sensing ethanol vapours. However, in the present work mixed oxide CdO-MnO₂ thin film is employed for ethanol sensing with short response and recovery time. Moreover, CdO-MnO₂ can detect ethanol vapours at ambient temperature. The other point to be highlighted is at ambient temperature the sensor response increases to 80% for ethanol which can be concluded that CdO-MnO₂ mixed oxide can be used as a reliable sensor to detect ethanol vapour in the mixed gas environment.

3.6 Formaldehyde vapour sensing mechanism

Formaldehyde is one of the carcinogens which are found in formalin solutions, condensation of polymerization used in paints and building materials and in industrial chemical process.⁴⁴⁻⁴⁶ Occupational Safety and Health Administration (OSHA) has set the threshold level of 20 ppm. Thus monitoring the formaldehyde level in air atmosphere is important for human health. Initially the mixed oxide film of CdO-MnO₂ is exposed to air, for oxygen to get adsorbed on to the film surface as represented in Eq. (1). As such, when the mixed oxide film is exposed to formaldehyde, the decrease in the width of the depletion region occurs across the crystallite resulting in the decrease in film resistance. The catalytic activity will increase the number of oxygen adsorption over the mixed oxide film surface which enhances the formaldehyde sensing

characteristics. However, the formaldehyde sensing is enhanced only when the activation energy is given in the form of thermal energy. Moreover the sensing mechanism of formaldehyde is more favorable only at a temperature of 393 K. At ambient temperature, the catalytic activity is not favorable for formaldehyde sensing however good for ethanol. The response towards formaldehyde sensing is nearly 0% for pure CdO and pure MnO₂ thin films. Fig. 13 represents resistance and response versus concentration plot. It is clearly observed under ambient air atmosphere, the film resistance is around 6 GΩ, upon exposure to formaldehyde vapours and it decreases the resistance to 4.29 GΩ for 30 ppm concentration. Further increase in the concentration to 90 ppm makes the resistance of the film to drop drastically to 1 GΩ. The response of the mixed oxide film increases from 37 % for 30 ppm to 600 % for 90 ppm concentration. From the observation it is clearly inferred that CdO-MnO₂ mixed oxide film can be used as a chemiresistor for efficient formaldehyde detection.

3.7 Response and recovery studies of Formaldehyde

Fig. 14 illustrates the transient response of CdO-MnO₂ film for different concentration. Usually the metal oxide semiconductor based vapour detection is not linear for the wide range of vapour concentration. This is because of measurement method, carrier injection due to reducing process and operating temperature. In the present studies, we observed that above 30 ppm, a significant change in electrical resistance and may be due the injected number of carrier concentration which is high. To measure this electrical resistance, the film has to be biased with constant current / voltage. In the present studies the measurement were made by fixing the voltage of 20Vdc. Hence, below this concentration much variation may not be observed and called as the dead band. However, increase in operating temperature for detection of formaldehyde is necessary to activate the process; the optimum temperature for formaldehyde

sensing is around 393 K. The fine crystallites of CdO-MnO₂ increase the sensitivity for higher concentrations of formaldehyde. As soon as the formaldehyde vapours are evacuated, the film reaches its baseline resistance. Fig. 15 shows the repeatability curve of formaldehyde vapour sensing at a concentration of 30 ppm at 393 K. The change in resistance is clearly observed upon exposure of formaldehyde vapour on CdO-MnO₂ film. Moreover, the paths traced during the cycles of operations are similar. Fig. 16 illustrates the response time, recovery time versus concentration of formaldehyde vapours. For lower concentration of 30 ppm, the response time is around 30 seconds, on increasing formaldehyde concentration to 90 ppm, the response time significantly decreases to 9 seconds at the temperature of 393 K. This clearly indicates that at higher concentration, desorption of oxygen ions are more favorable. In contrast, the recovery time increases due to the complete depletion of grains with formaldehyde vapours. The response time and recovery time is in the order of seconds which infers that the prepared mixed oxides of CdO-MnO₂ are highly sensitive towards formaldehyde vapours. Fig. 17 refers the sensing response and selectivity of formaldehyde towards other interfering vapours. The response is around 600% for 90 ppm of formaldehyde vapours. Besides, the response of other reducing vapours is less than 100 % for 90 ppm this clearly indicates that CdO-MnO₂ film is highly selective towards formaldehyde vapours. From the selectivity plot it is inferred that even in mixed vapour environment the mixed oxide film is sensitive to formaldehyde vapours. Table 2 compares the formaldehyde sensing parameters with different types of nanostructured HCHO sensors.⁴⁷⁻⁵¹ From the previous reports it is inferred for formaldehyde sensing; the response-recovery time is long. However, selectivity towards formaldehyde than other vapours is also a challenging task. Moreover, in the present work mixed CdO-MnO₂ thin film is used to detect formaldehyde vapour at 393 K with enhanced selectivity. Analyzing all these factors it can be

concluded that CdO-MnO₂ mixed oxide film is a promising material to detect formaldehyde vapours. Fig. 18 represents the response of ethanol and formaldehyde vapour for different temperature. It is clearly evident from the plot that response is appreciable for ethanol for ambient temperature. For higher temperature, the response is observed to be high for formaldehyde vapours. Fig 19 shows the response of pure CdO and pure MnO₂ films towards ethanol and formaldehyde at 300 K and 393 K. For pure CdO and pure MnO₂ film the response is around 0 % at 300 K. However, for pure CdO at 393 K the response to ethanol is 3 % and response to formaldehyde is 1 % and for pure MnO₂ film it is around 0 % for both ethanol and formaldehyde vapours. At high temperature, the ethanol may partially get dissociated before oxidation. Hence the response at elevated temperature decreases for mixed oxide film.

3.8 Stability and reproducibility of mixed oxide CdO-MnO₂ film

The sensing stability and reproducibility of mixed oxide CdO-MnO₂ are studied for 45 ppm concentration of ethanol and formaldehyde vapours at 300 K and 393 K respectively. Fig. 20 represents the stability of CdO-MnO₂ thin film as a function of time for 45 ppm ethanol and formaldehyde vapour. The measurement is carried out for a period of 180 days in intervals of 30 days. The response of mixed oxide CdO-MnO₂ film remains steady for ethanol and formaldehyde vapours. The response for ethanol is in the order of 75 % at ambient temperature, whereas for formaldehyde the response is in the order of 60 % at the temperature of 393 K. This confirms that the prepared film is stable and reproducibility can be attained over the period of time.

3.9 Humidity effect on sensing properties of mixed CdO-MnO₂ film

Relative Humidity (RH) plays an important role in the sensing characteristics of mixed CdO-MnO₂ film at ambient temperature. The influence of humidity on the sensing properties of ethanol and formaldehyde on mixed CdO-MnO₂ film is studied by creating humid environment

using saturated salt solutions namely KCl, NaCl and MgCl₂ solutions (RH = 84%, 75% and 33% respectively) in the vapour sensing chamber and RH is measured with hygrometer (RH of \pm 1% is maintained). Upon exposing the film towards humid air, two mechanisms may take place; the water molecule gets adsorbed over the surface of film in molecular or hydroxyl form, which further donates the electrons to nanocrystallites. In other way, water molecule replaces the adsorbed oxygen ions and releases the electrons from the ionized oxygen atoms. In the above two mechanisms, the donor effect results to increase in the electron concentration in the conduction band of and decreases the electrical resistance of the film. The sensing response of the film for different humidity levels is calculated using Eq. (5) as,

$$\% S_{RH} = \frac{(R_{RH} - R_{RH+ vapour})}{R_{RH+ vapour}} \times 100 \quad \text{-----(5)}$$

Where R_{RH} and $R_{RH+ vapour}$ represents the resistance of the mixed oxide film in humid air and humid + vapour (ethanol or formaldehyde) environment respectively. Fig. 21 represents the ethanol and formaldehyde sensing response at different relative humid environment. The vapour sensing response of mixed CdO-MnO₂ decreases upon increase in RH. For low RH, water molecules chemisorb on oxygen vacant sites, which in turn decrease the response. Moreover, for high RH, the water molecules may be physisorbed due to capillary condensation. This significantly decreases the interaction of ethanol and formaldehyde in the film surface, further decreases the response.

4. Conclusion

The mixed oxide CdO-MnO₂ thin films are synthesized using home-built spray pyrolysis unit. The crystallinity and mixed oxides states of thin films are confirmed with XRD and EDAX results. When CdO-MnO₂ film is exposed to ethanol vapours, the film resistance decreases

drastically. The optimum concentration of ethanol vapours ranges from 15 ppm to 75 ppm at ambient temperature. The prepared CdO-MnO₂ is highly selective towards ethanol at ambient temperature than other vapours. The prepared CdO-MnO₂ is highly sensitive to ethanol vapours at the operating temperature of 300 K. At 393 K, CdO-MnO₂ film is highly selective towards formaldehyde than other interfering vapours. The response of CdO-MnO₂ is optimum for the concentration of 30 ppm to 90 ppm for formaldehyde. From the results it is concluded that the mixed oxide CdO-MnO₂ film can be used for ethanol and formaldehyde sensing.

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Figure captions

Fig. 1. X-ray diffraction pattern of CdO-MnO₂ mixed oxide film.

Fig. 2. Field-emission scanning electron micrograph of CdO-MnO₂ mixed thin film.

Fig. 3. Energy dispersive X-ray spectrum of CdO-MnO₂ mixed oxide thin film.

Fig. 4. Elemental mapping of CdO-MnO₂ mixed oxide film.

Fig. 5. Optical transmittance spectrum of CdO-MnO₂ mixed oxide thin film.

Fig. 6. Tauc's plot of CdO-MnO₂ mixed oxide thin film.

Fig. 7. Variation in electrical resistance and sensing response of CdO-MnO₂ thin film for various ethanol concentrations at 300 K.

Fig. 8 (a) CdO-MnO₂ molecular device model with gold electrodes (b) Adsorption of ethanol molecule on manganese atom in CdO-MnO₂ molecular device.

Fig. 9. Transient response of CdO-MnO₂ films towards various concentrations of ethanol.

Fig. 10. Resistance repeatability plot of CdO-MnO₂ film for 30 ppm of ethanol.

Fig. 11. Response time and recovery time of the film versus concentration of ethanol.

Fig. 12. Sensing response and selectivity of CdO-MnO₂ mixed oxide thin film towards various concentrations of ethanol and other volatile organic compounds at 300K.

Fig. 13. Variation in electrical resistance and sensing response of CdO-MnO₂ thin film for various formaldehyde concentrations at 393 K.

Fig. 14. Transient response of CdO-MnO₂ films towards various concentrations of formaldehyde.

Fig. 15. Resistance repeatability plot of CdO-MnO₂ film for 30 ppm formaldehyde.

Fig. 16. Response time and recovery time versus concentration of formaldehyde.

Fig. 17. Sensing response and selectivity of CdO-MnO₂ mixed oxide thin film towards various concentrations of formaldehyde and other volatile organic compounds at 393 K.

Fig. 18. Response of ethanol and formaldehyde plot for different temperature.

Fig. 19. Response of pure CdO and pure MnO₂ films to ethanol and formaldehyde.

Fig. 20. Stability of CdO-MnO₂ thin film as a function of time for 45 ppm ethanol and formaldehyde vapour.

Fig. 21. Ethanol and formaldehyde vapour response in different relative humid environment at 300 K

Table captions

Table.1 Comparison of ethanol sensing characteristics of chemiresistive sensors with the present work.

Table.2 Comparison of formaldehyde sensing characteristics of chemiresistive sensors with the present work.

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Fig. 1.

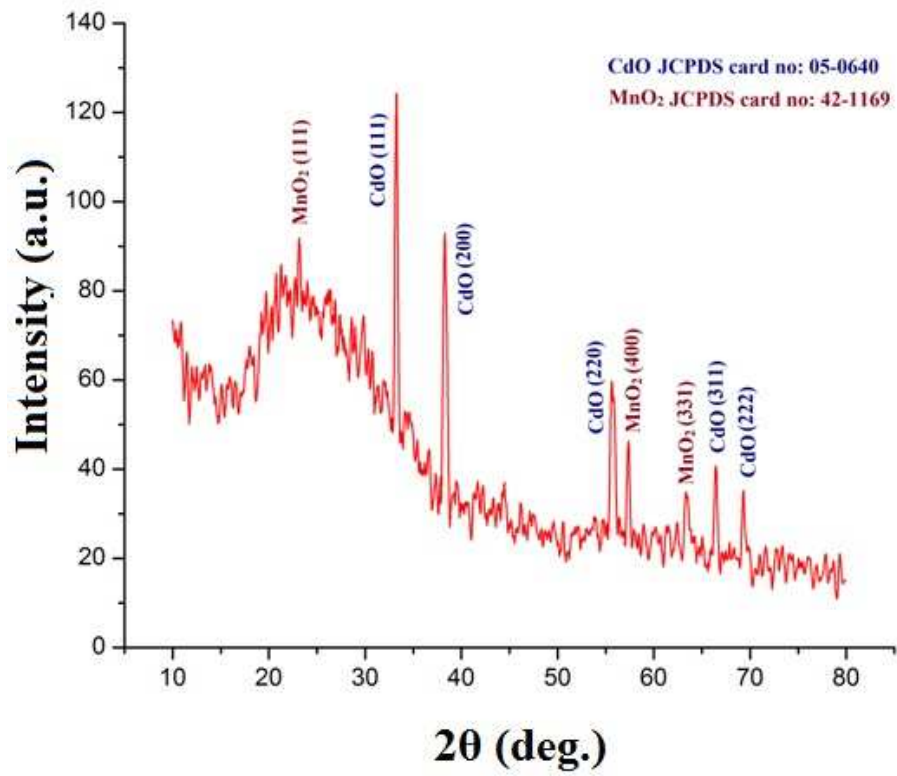


Fig. 2.

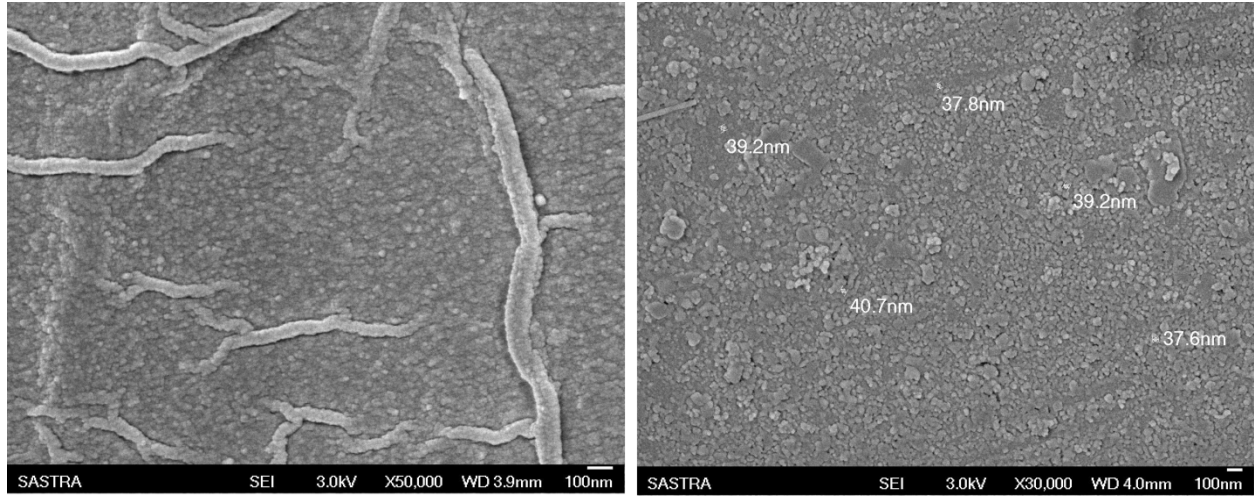


Fig. 3.

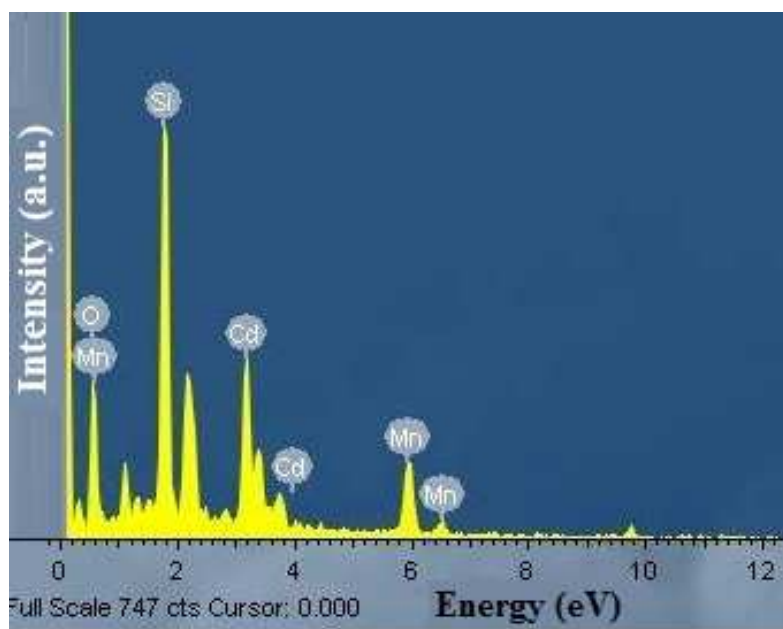


Fig. 4.

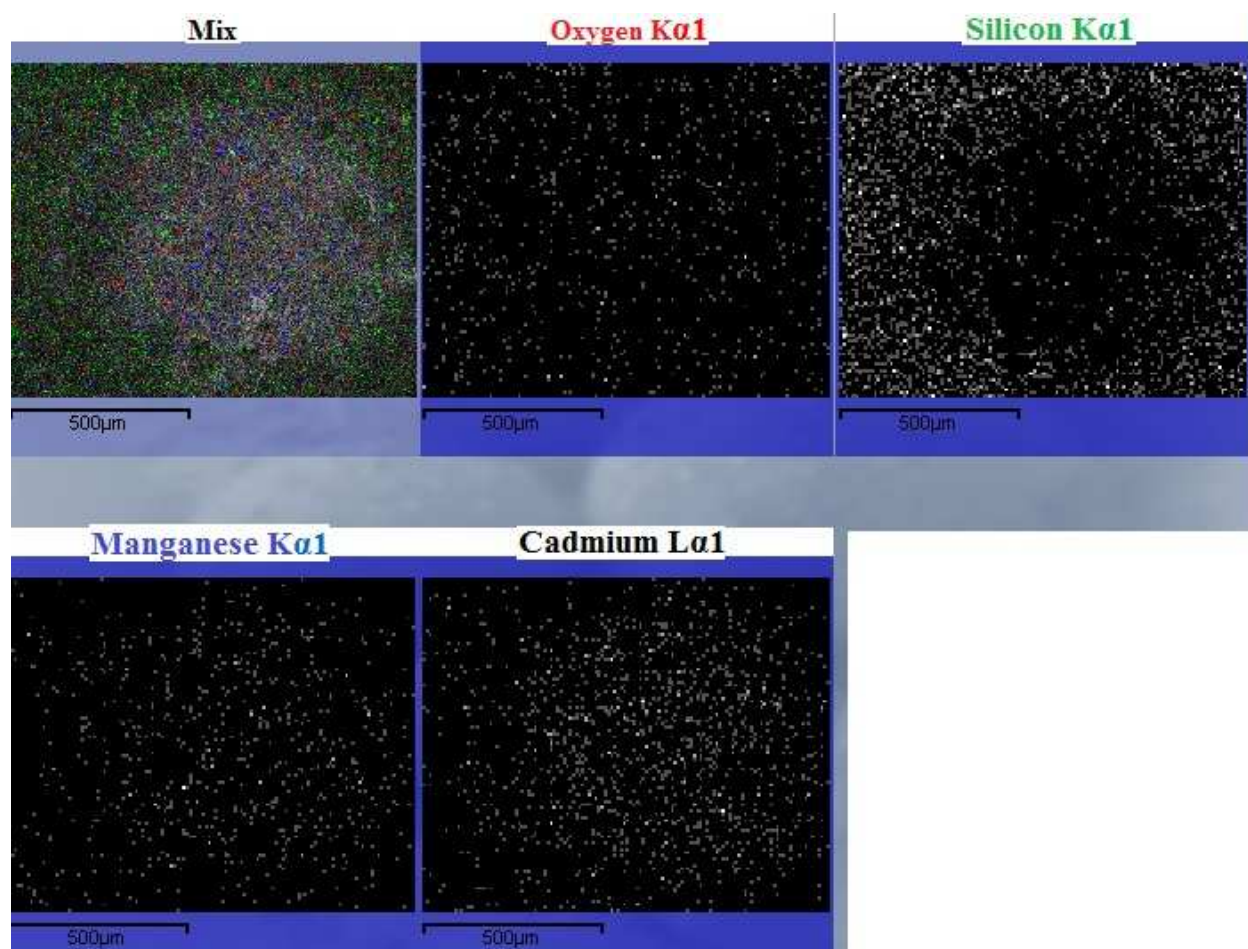


Fig. 5

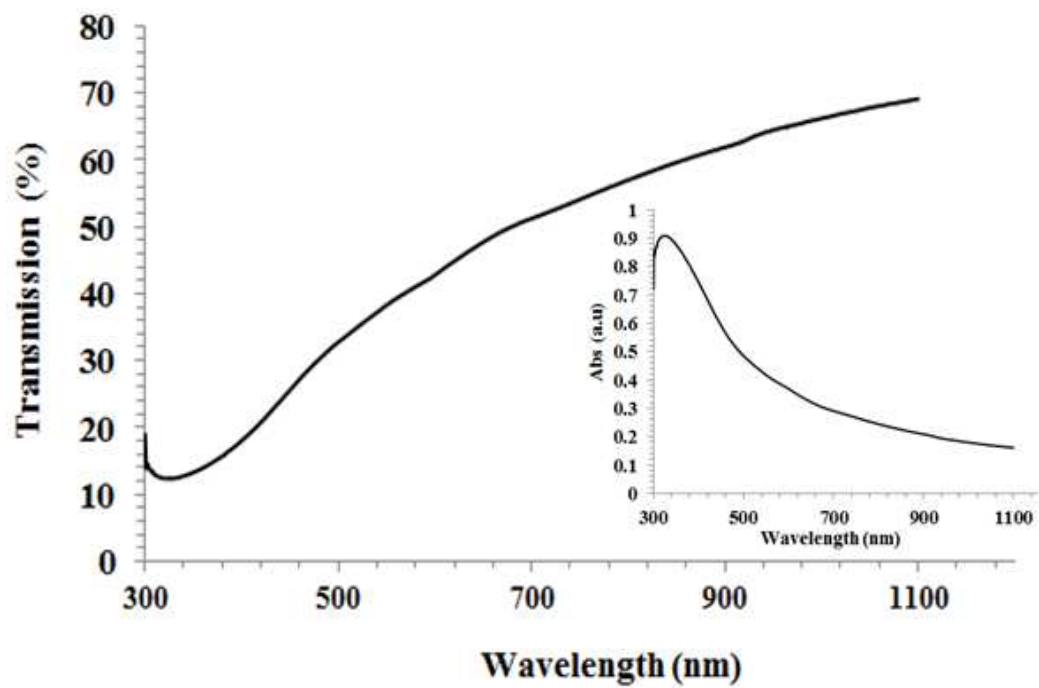


Fig. 6.

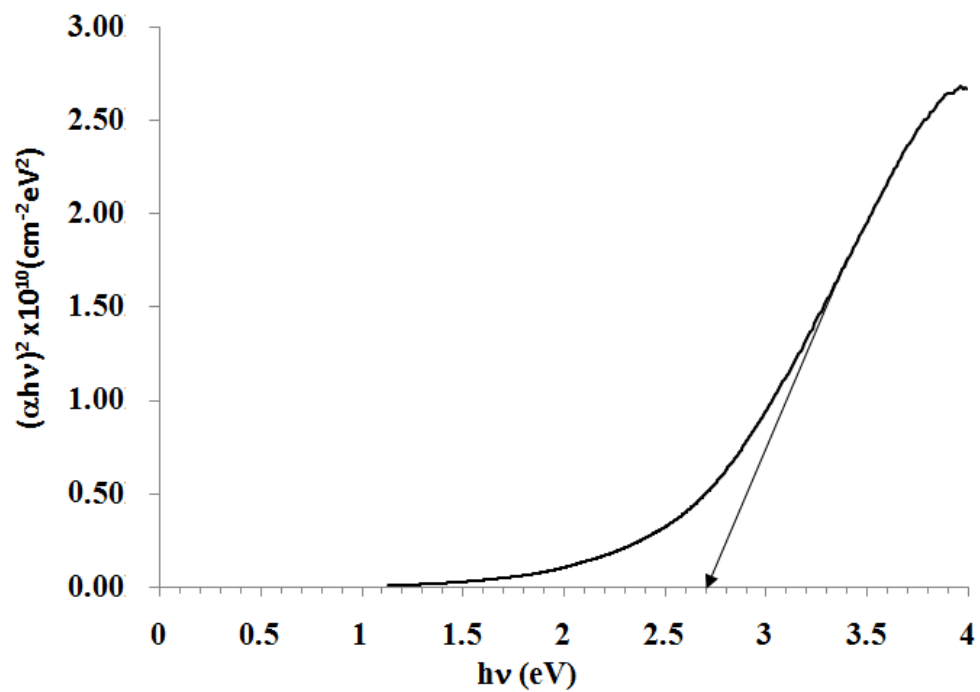


Fig. 7.

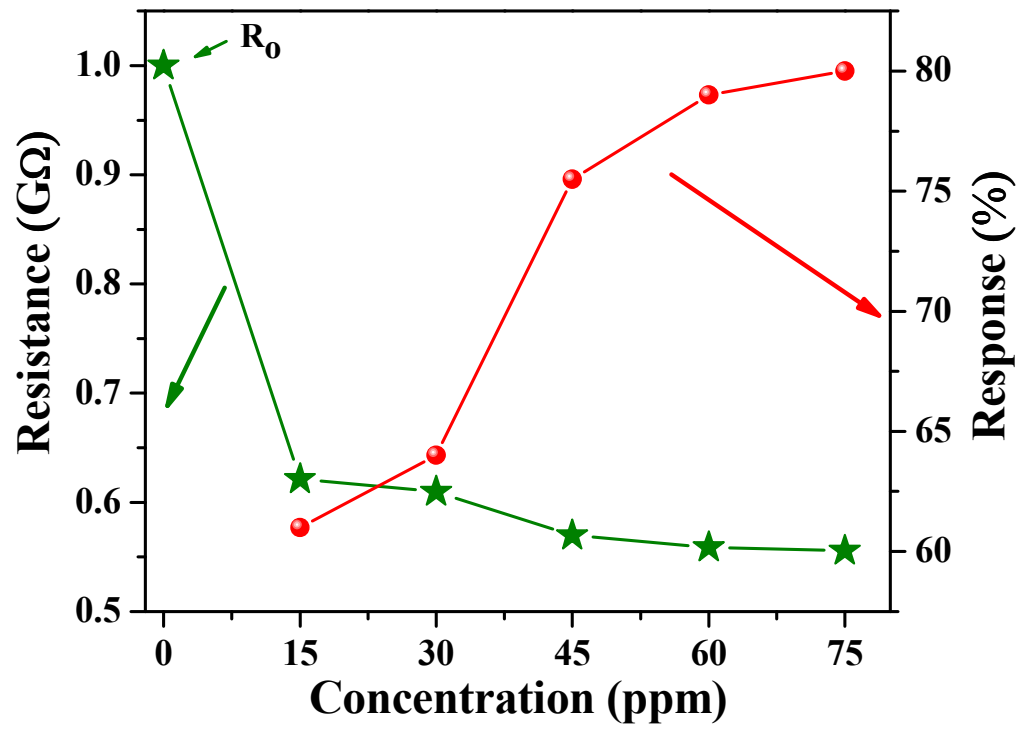


Fig. 8 (a).

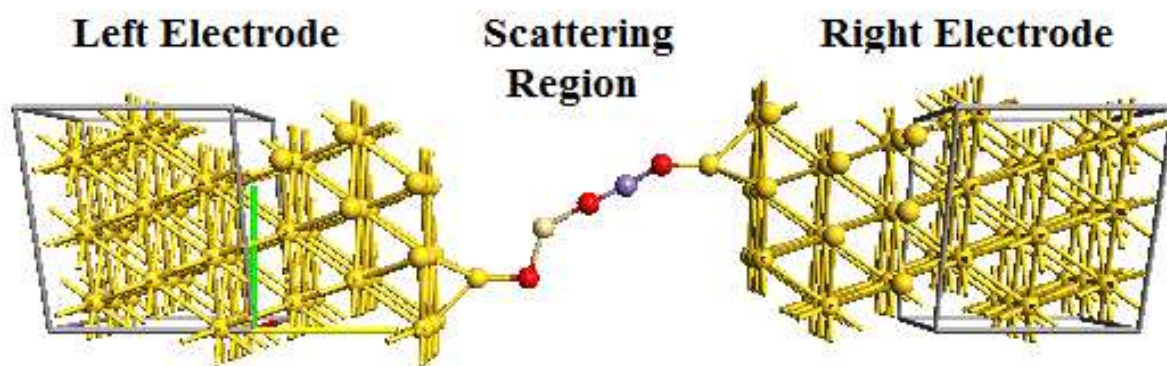


Fig. 8 (b)

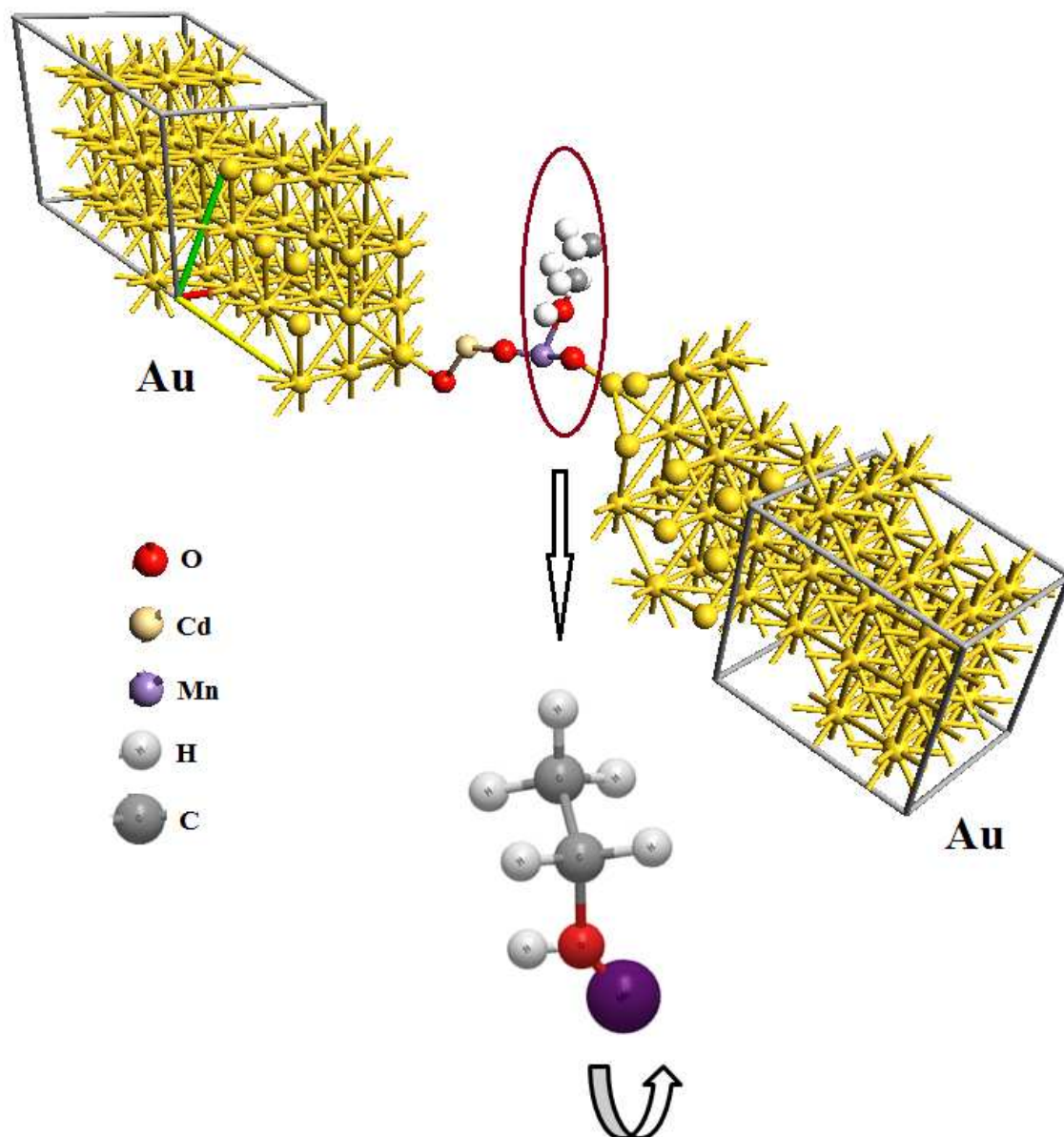


Fig. 9.

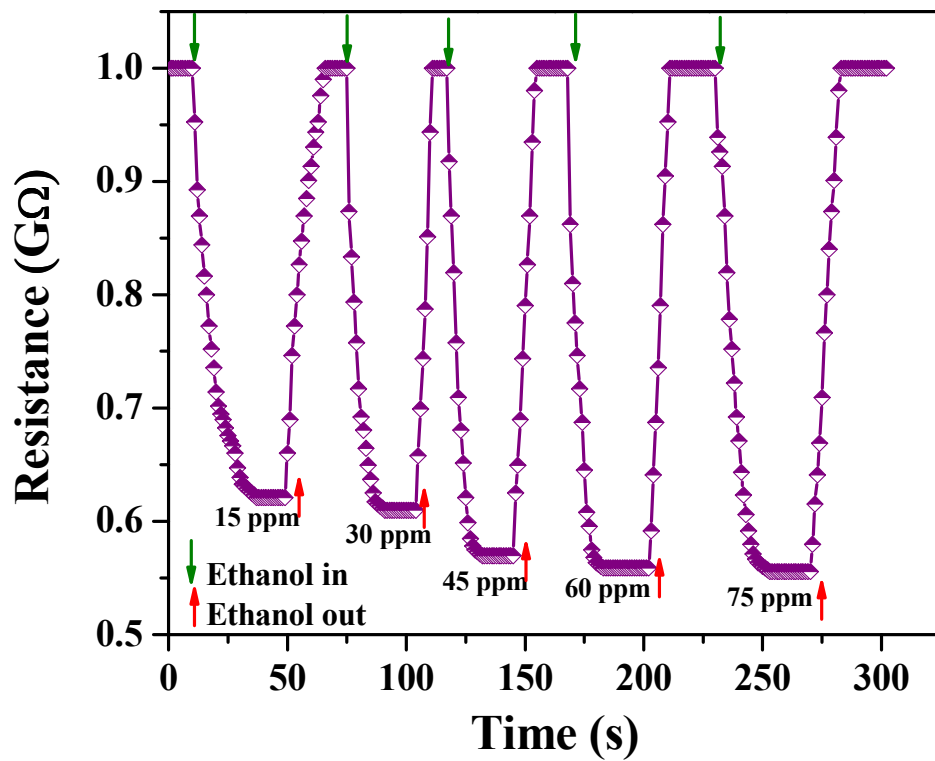


Fig. 10.

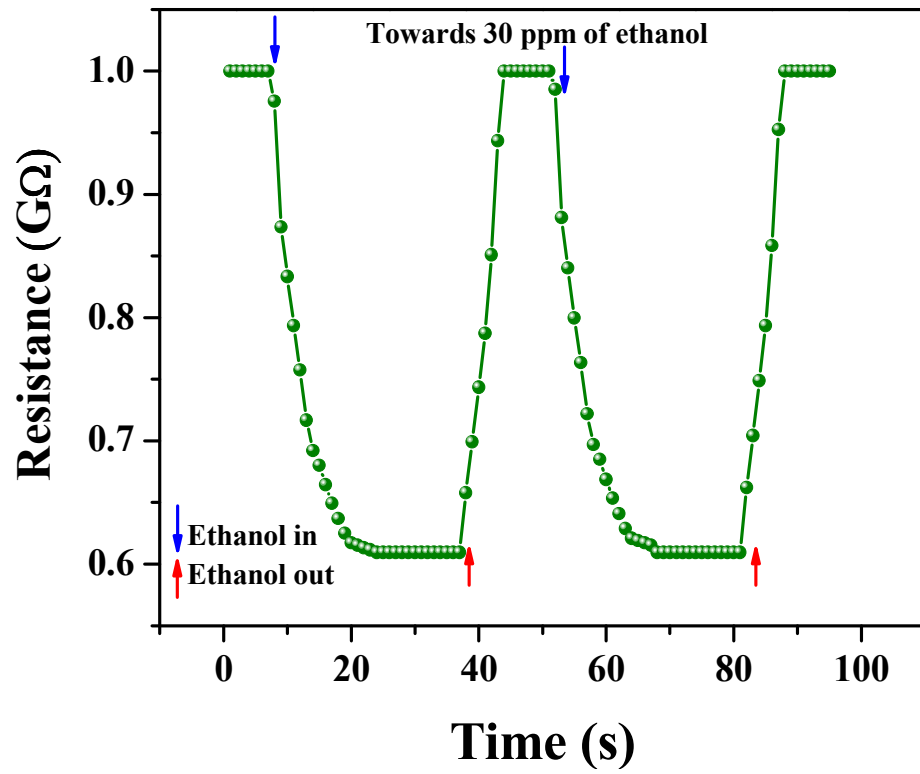


Fig. 11.

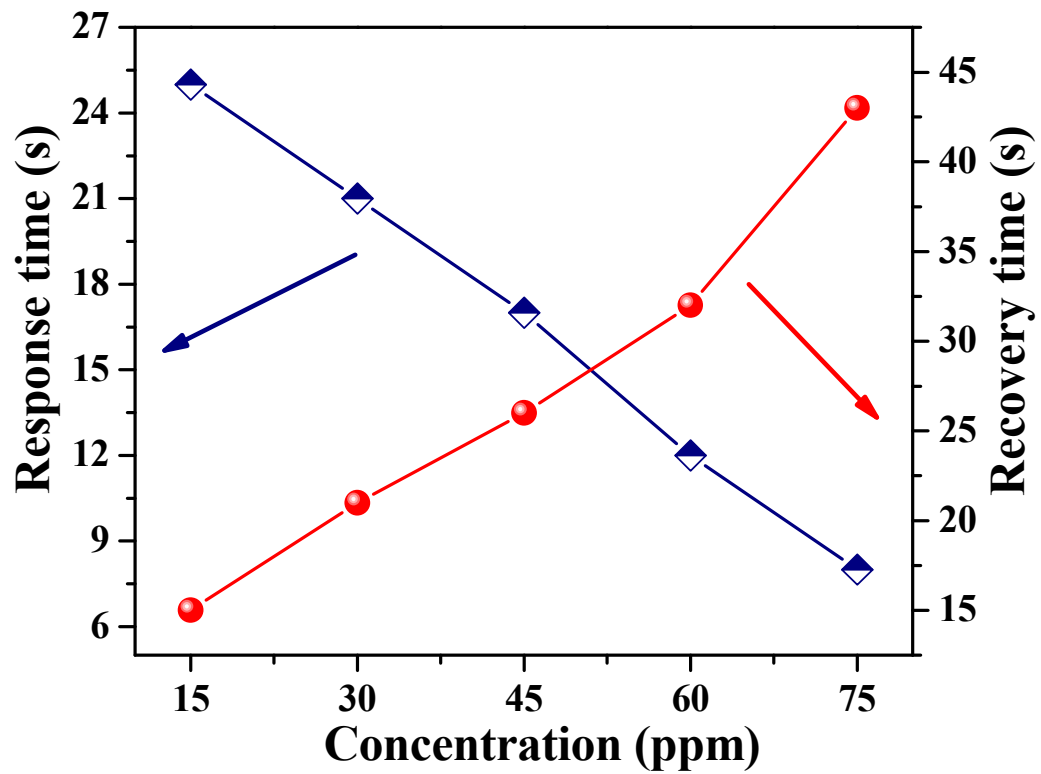


Fig. 12.

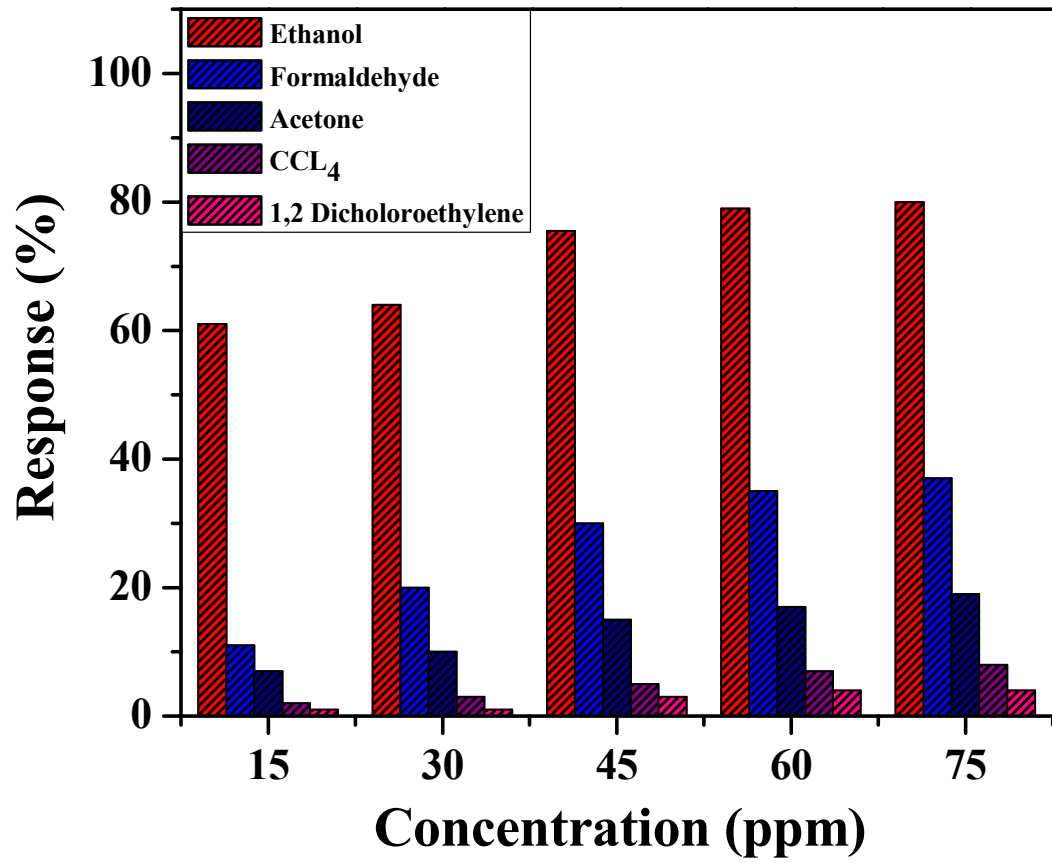


Fig. 13.

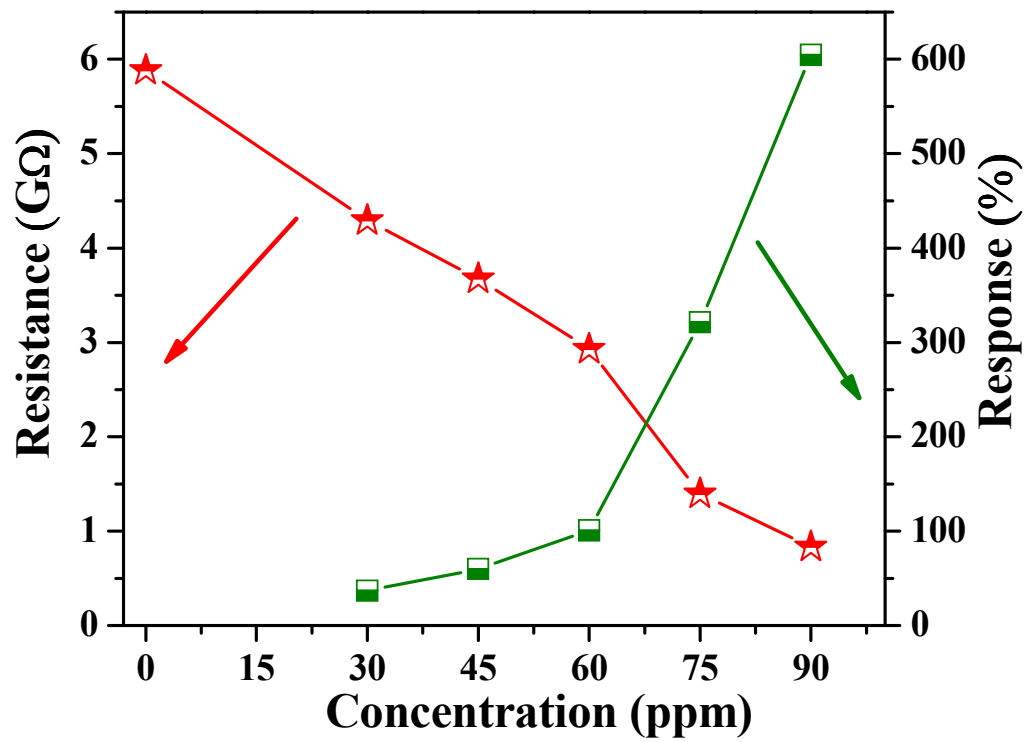


Fig. 14.

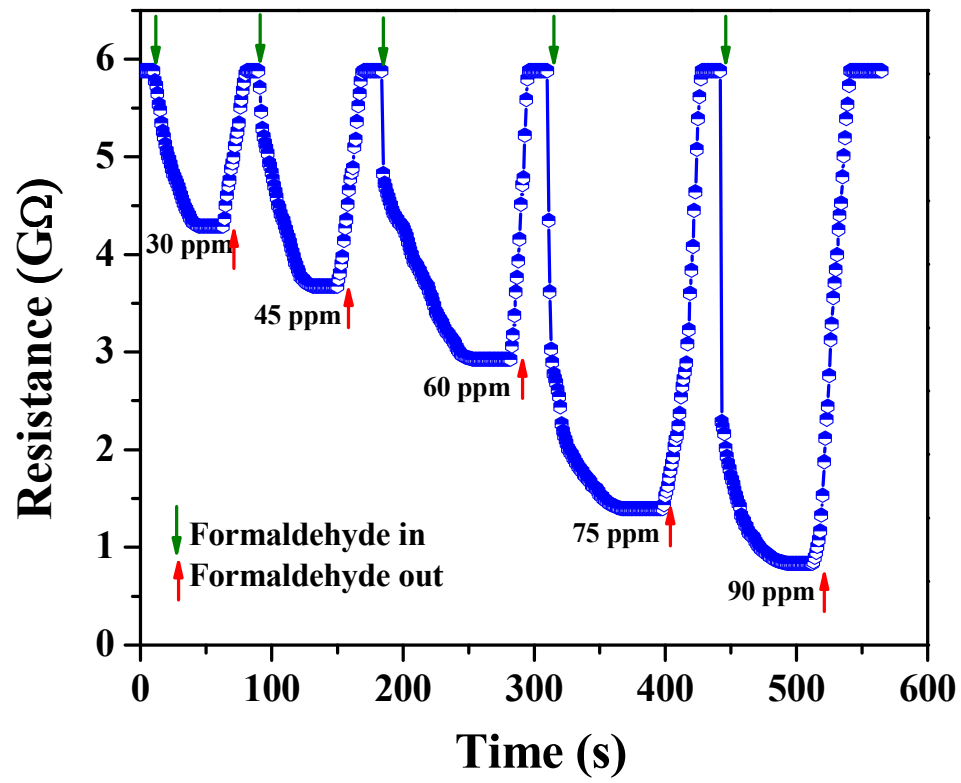


Fig. 15.

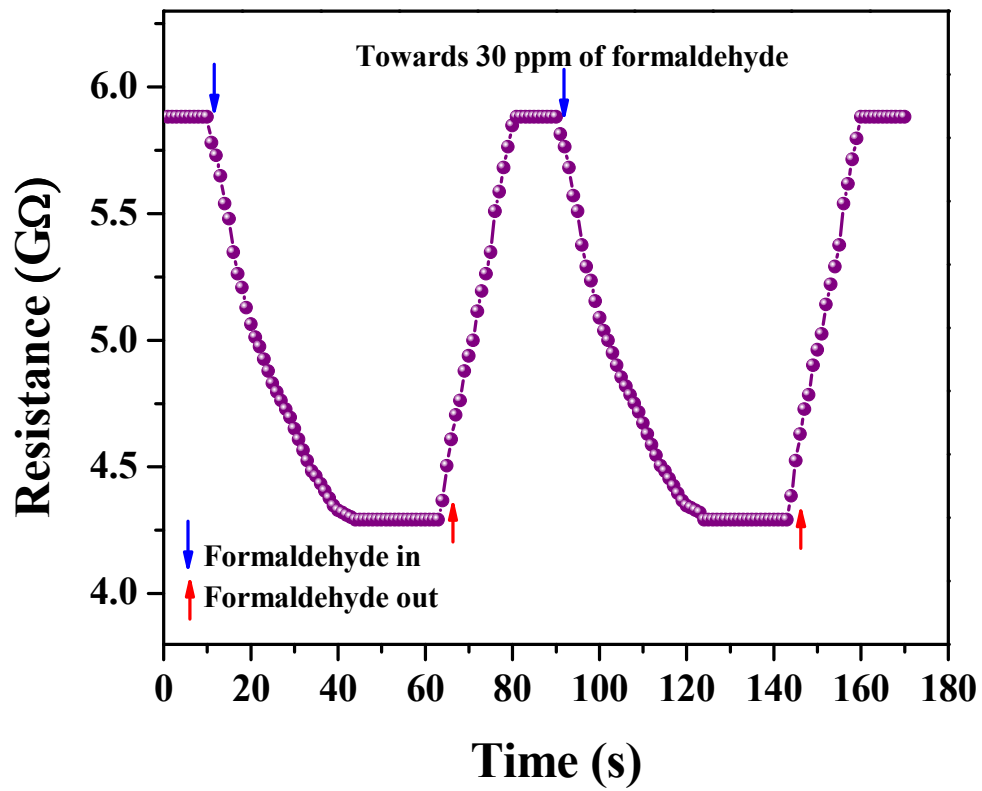


Fig. 16.

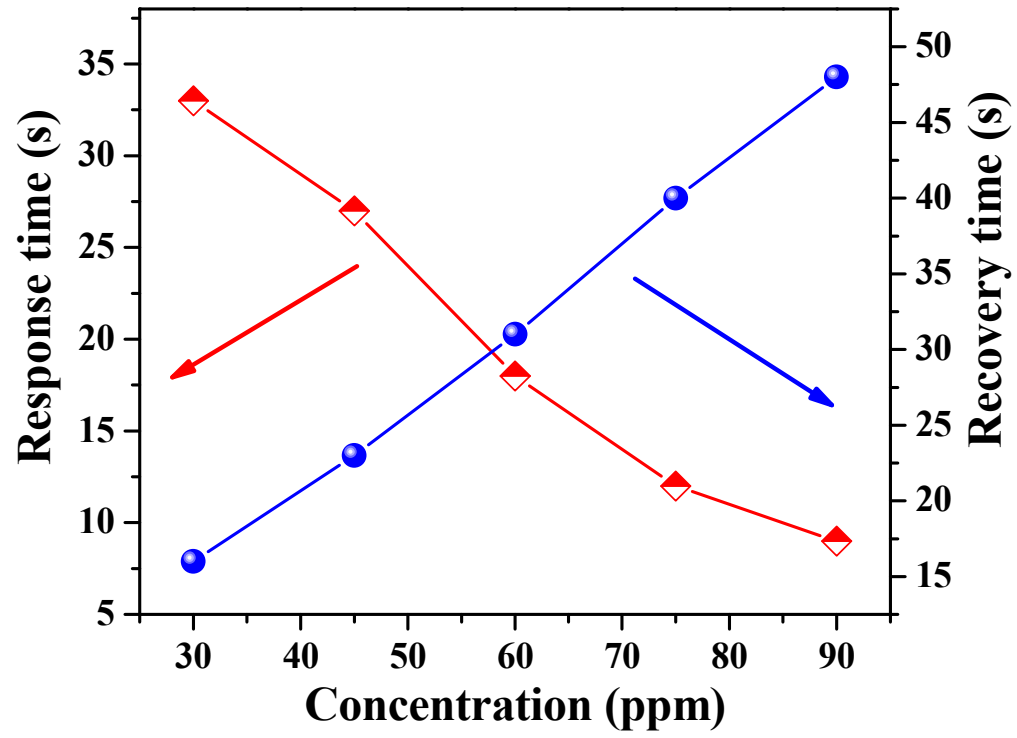


Fig. 17.

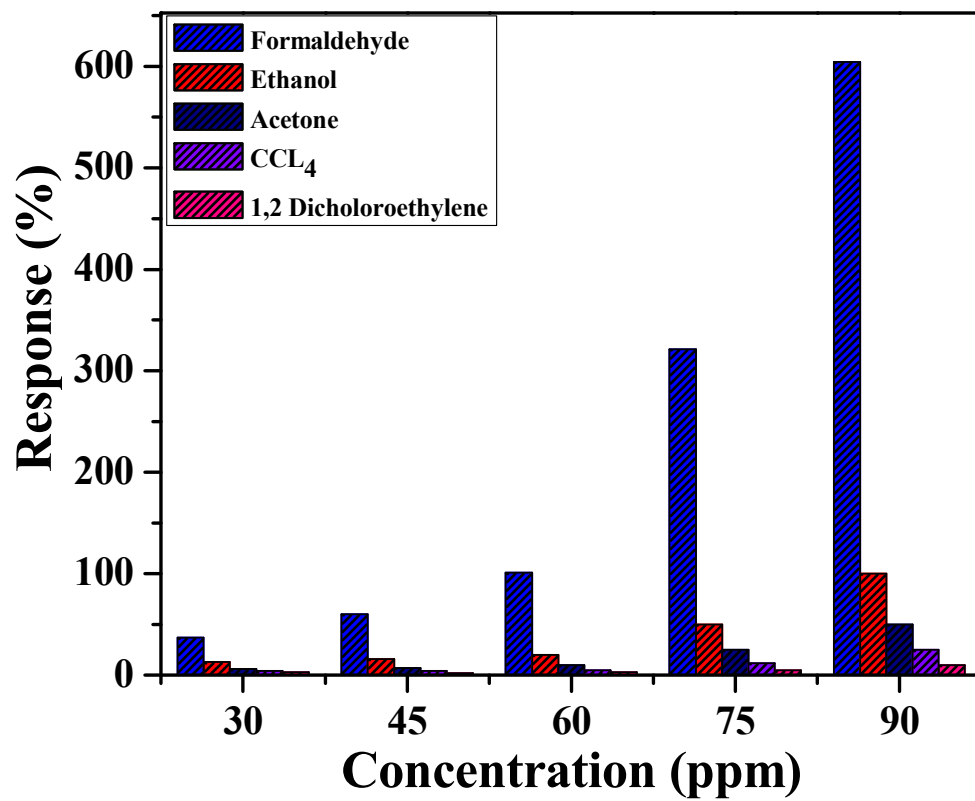


Fig. 18.

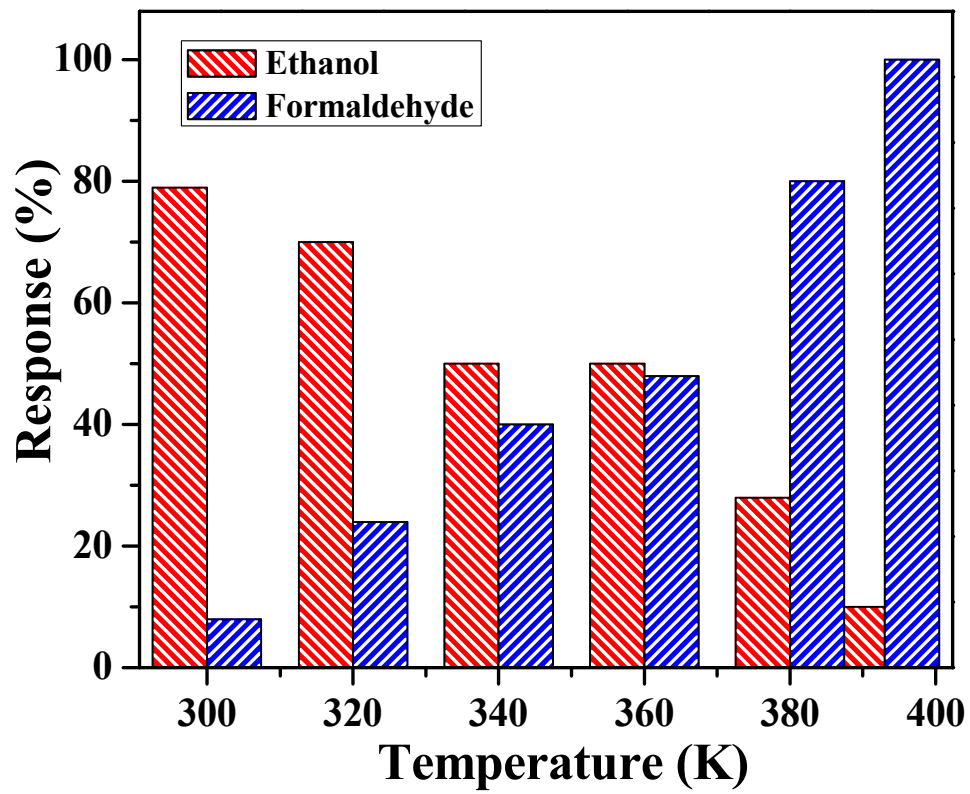


Fig. 19.

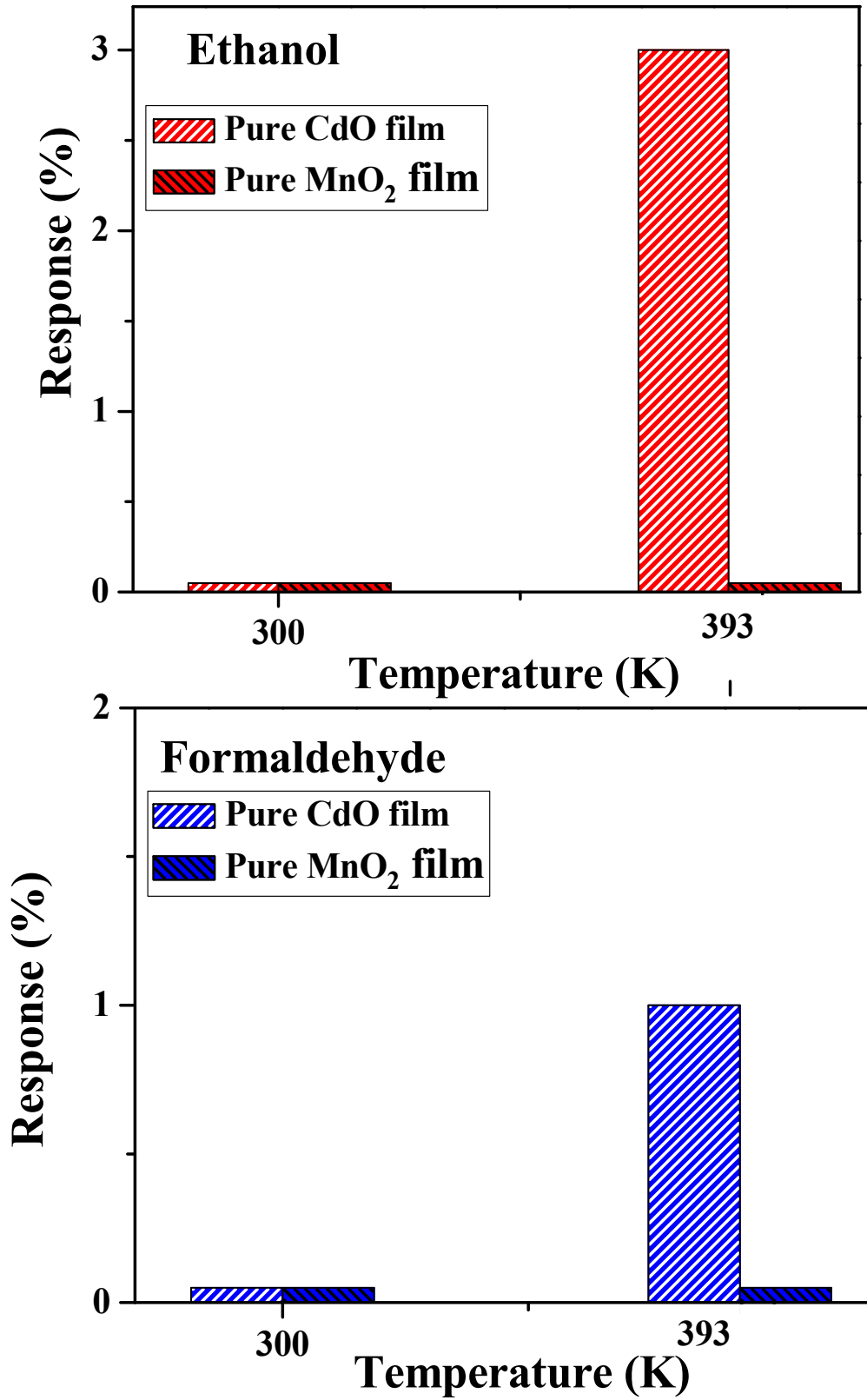


Fig. 20.

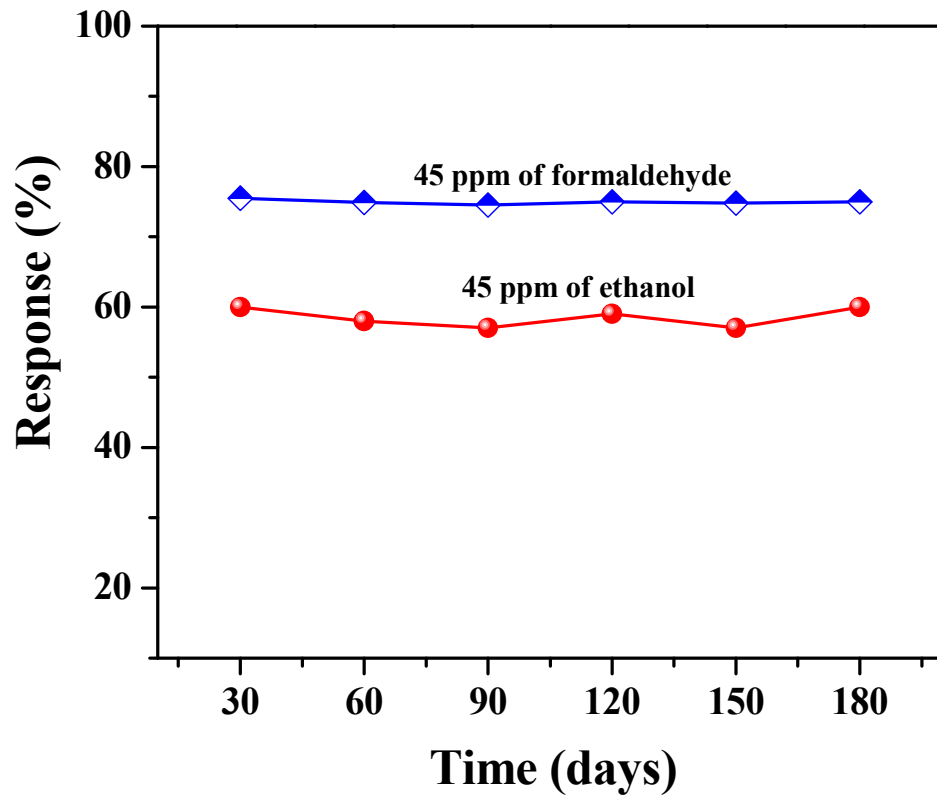


Fig. 21.

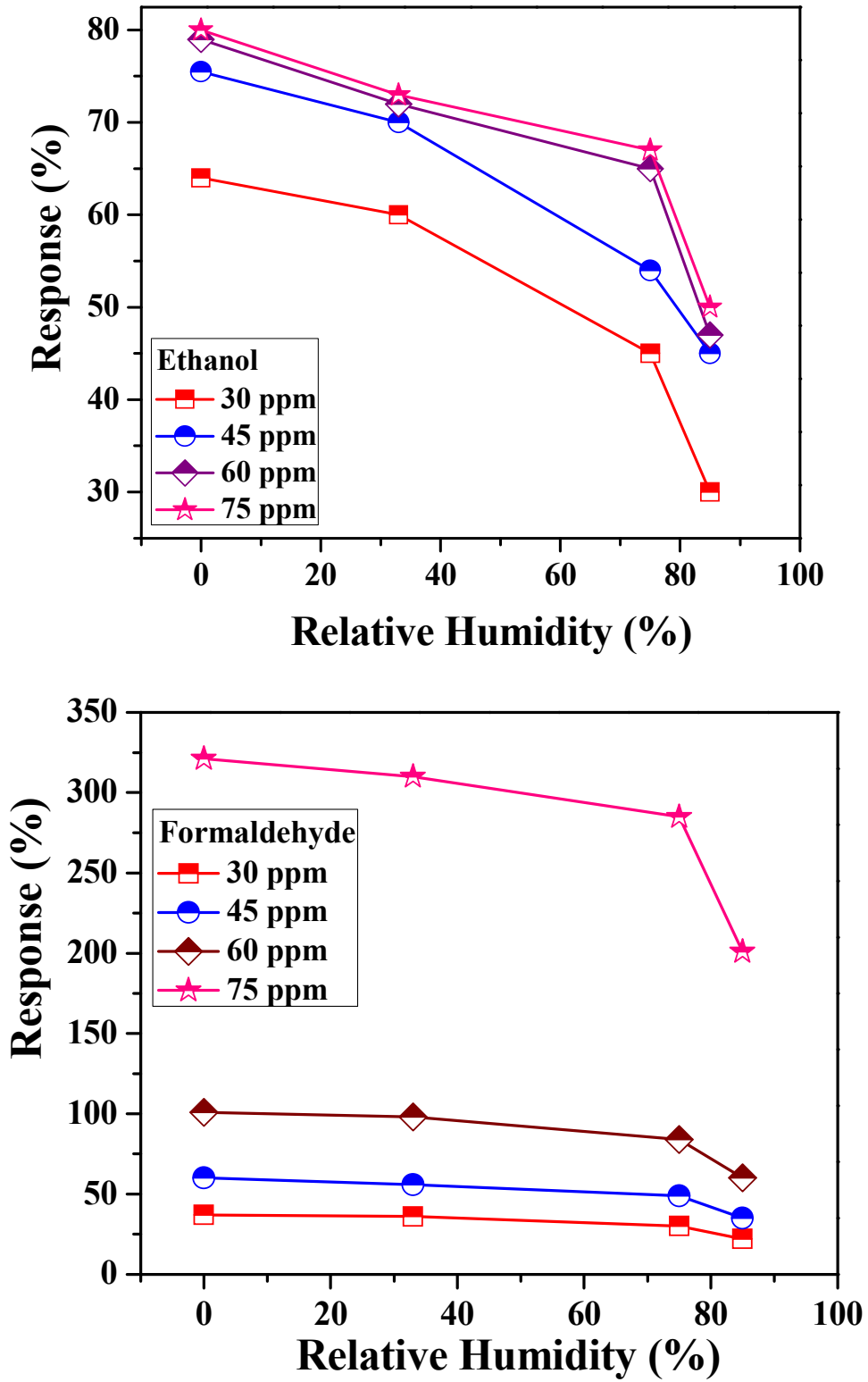


Table 1.

Metal Oxide	Preparation Method	Detection range (ppm)	Operating temperature (°C)	Response time (s)	Recovery time (s)	Ref.
TiO ₂	Anodizing Ti foils	50-1000	250	24-110	6-20	37
TiO ₂	Sol-gel dip	10-50	30	65	20	38
In ₂ O ₃	Hydrothermal	50-500	275	16	24	39
ZnO	Electrospinning	10-150	270	7-9	9-11	40
CeO ₂	Spray pyrolysis	5-50	100	35	65	41
CuO-In ₂ O ₃	RF sputtering	50-250	300	36-53	149-153	42
ZnO-CdO	Spray pyrolysis	10-150	100	48	60	43
CdO-MnO ₂	Spray pyrolysis	15-75	30	15-25	8-42	Present work

Table 2.

Metal Oxide	Preparation Method	Detection range (ppm)	Operating temperature (°C)	Response time(s)	Recovery time(s)	Ref.
Fe ₂ O ₃ -In ₂ O ₃	Electrospinning	1-10000	250	5	25	47
In ₂ O ₃	Ammonolysis and re-oxidation	5-100	420	48	58	48
SnO ₂	Screen printing	1-100	210-410	4-57	19-60	49
NiO-SnO ₂	Electrospinning	1-10	200	50	80	50
ZnO	Hydrothermal	10-1000	400	41	15	51
CdO-MnO ₂	Spray pyrolysis	30-90	120	16-32	8-47	Present work